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View Online at https://aerobasegroup.com/nsn/5962-01-301-8506 **Body Length:** 0.458 inches **Body Width:** 0.560 inches **Body Height:** 0.120 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and electrostatic sensitive and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Case Outline Source And Designator:** C-12 mil-m-38510 **Current Rating Per Characteristic:** 70.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 90.00 nanoseconds access **Memory Device Type:** Ram **Terminal Type And Quantity:** 32 leadless Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No

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